

Half-Duplex, iCoupler[®] Isolated RS-485 Transceiver

Data Sheet ADM2483

FEATURES

RS-485 transceiver with electrical data isolation
Complies with ANSI TIA/EIA RS-485-A and ISO 8482: 1987(E)
500 kbps data rate
Slew rate-limited driver outputs
Low power operation: 2.5 mA max
Suitable for 5 V or 3 V operations (VDD1)
High common-mode transient immunity: >25 kV/µs
True fail-safe receiver inputs
Chatter-free power-up/power-down protection
256 nodes on bus
Thermal shutdown protection
Safety and regulatory approvals
UL recognition: 2500 V rms for 1 minute per UL 1577

CSA Component Acceptance Notice 5A
IEC 609501 800 V rms (basic), 400 V rms (reinforced)

VDE Certificate of Conformity
DIN V VDE V 0884-10 (VDE V 0884-10): 2006-12

V_{IORM} = 560 V peak

CQC certification per GB4943.1-2011 Operating temperature range: -40°C to +85°C

APPLICATIONS

Low power RS-485/RS-422 networks Isolated interfaces Building control networks Multipoint data transmission systems

GENERAL DESCRIPTION

The ADM2483 differential bus transceiver is an integrated, galvanically isolated component designed for bidirectional data communication on balanced, multipoint bus transmission lines. It complies with ANSI EIA/TIA-485-A and ISO 8482: 1987(E). Using Analog Devices' *i*Coupler technology, the ADM2483 combines a 3-channel isolator, a three-state differential line driver, and a differential input receiver into a single package. The logic side of the device is powered with either a 5 V or 3 V supply, and the bus side uses a 5 V supply only.

The ADM2483 is slew-limited to reduce reflections with improperly terminated transmission lines. The controlled slew rate limits the data rate to 500 kbps. The device's input impedance is 96 k Ω , allowing up to 256 transceivers on the bus. Its driver has an active-high enable feature. The driver differential outputs

FUNCTIONAL BLOCK DIAGRAM

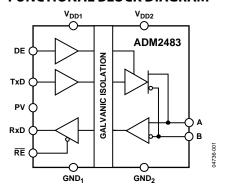


Figure 1.

and receiver differential inputs are connected internally to form a differential I/O port. When the driver is disabled or when $V_{\rm DD1}$ or $V_{\rm DD2}$ = 0 V, this imposes minimal loading on the bus. An active-high receiver disable feature, which causes the receive output to enter a high impedance state, is provided as well.

The receiver inputs have a true fail-safe feature that ensures a logic-high receiver output level when the inputs are open or shorted. This guarantees that the receiver outputs are in a known state before communication begins and at the point when communication ends.

Current limiting and thermal shutdown features protect against output short circuits and bus contention situations that might cause excessive power dissipation. The part is fully specified over the industrial temperature range and is available in a 16-lead, wide body SOIC package.

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ADM2483* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS \Box

View a parametric search of comparable parts.

EVALUATION KITS

ADM2483 Evlauation Board

DOCUMENTATION

Application Notes

- AN-0971: Recommendations for Control of Radiated Emissions with isoPower Devices
- AN-1176: Component Footprints and Symbols in the Binary .Bxl File Format
- AN-1179: Junction Temperature Calculation for Analog Devices RS-485/RS-422, CAN, and LVDS/M-LVDS Transceivers
- AN-727: iCoupler® Isolation in RS-485 Applications
- AN-740: iCoupler® Isolation in RS-232 Applications
- AN-793: ESD/Latch-Up Considerations with iCoupler® Isolation Products
- AN-825: Power Supply Considerations in iCoupler® Isolation Products
- AN-960: RS-485/RS-422 Circuit Implementation Guide

Data Sheet

 ADM2483: Half-Duplex iCoupler® Isolated RS-485 Transceiver Data Sheet

User Guides

 UG-239: Evaluation Board for the ADM2483 Half-Duplex iCoupler Isolated RS-485 Transceiver

SOFTWARE AND SYSTEMS REQUIREMENTS —

- ADI RS-485/RS-422 Cross Reference Guide
- RS-232 Transceivers Cross Reference Guide

REFERENCE MATERIALS 🖳

Press

 Analog Devices Achieves Major Milestone by Shipping 1 Billionth Channel of iCoupler Digital Isolation

Product Selection Guide

• Digital Isolator Product Selection and Resource Guide

Solutions Bulletins & Brochures

- Emerging Energy Applications Solutions Bulletin, Volume 10, Issue 4
- Test & Instrumentation Solutions Bulletin, Volume 10, Issue 3

Technical Articles

- Inside iCoupler® Technology:ADuM347x PWM Controller and Transformer Driver with Quad-Channel Isolators Design Summary
- MS-2127: Designing with iCoupler Digital Isolators in Solar PV Inverters
- NAppkin Note: Lowering the Power of the ADuM524x

DESIGN RESOURCES \Box

- ADM2483 Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all ADM2483 EngineerZone Discussions.

SAMPLE AND BUY

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TECHNICAL SUPPORT 🖳

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DOCUMENT FEEDBACK

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REVISION HISTORY		
9/2016—Rev. D to Rev. E	3/2005—Rev. A to Rev. B	
Added Table 4; Renumbered Sequentially5	Change to Features	1
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Change to Features Section 1	Changes to Figure 9 and Figure 11	10
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Updated Outline Dimensions 18	10/2004—Revision 0: Initial Version	
Changes to Ordering Guide 18		

SPECIFICATIONS

 $2.7 \leq V_{DD1} \leq 5.5 \text{ V}, \, 4.75 \text{ V} \leq V_{DD2} \leq 5.25 \text{ V}, \, T_{A} = T_{MIN} \text{ to } T_{MAX} \text{, unless otherwise noted.}$

Table 1.

Parameter	Min	Тур	Max	Unit	Test Conditions/Comments
DRIVER					
Differential Outputs					
Differential Output Voltage, Vod			5	V	R = ∞, see Figure 3
	2.0		5	V	$R = 50 \Omega$ (RS-422), see Figure 3
	1.5		5	V	$R = 27 \Omega$ (RS-485), see Figure 3
	1.5		5	V	$V_{TST} = -7 \text{ V to } +12 \text{ V}, V_{DD1} \ge 4.75,$ see Figure 4
$\Delta V_{OD} $ for Complementary Output States			0.2	V	$R = 27 \Omega$ or 50Ω , see Figure 3
Common-Mode Output Voltage, Voc			3	V	$R = 27 \Omega$ or 50Ω , see Figure 3
$\Delta V_{OC} $ for Complementary Output States			0.2	V	$R = 27 \Omega$ or 50 Ω, see Figure 3
Output Short-Circuit Current, VOUT = High	-250		+250	mA	$-7 \text{ V} \leq \text{V}_{\text{OUT}} \leq +12 \text{ V}$
Output Short-Circuit Current, V _{OUT} = Low	-250		+250	mA	$-7 \text{ V} \leq \text{V}_{\text{OUT}} \leq +12 \text{ V}$
Logic Inputs					
Input High Voltage	0.7 V _{DD1}			V	TxD, DE, RE, PV
Input Low Voltage			0.25 V _{DD1}	V	TxD, DE, RE, PV
CMOS Logic Input Current (TxD, DE, RE, PV)	-10	+0.01	+10	μΑ	TxD, DE, \overline{RE} , PV = V_{DD1} or 0 V
RECEIVER					
Differential Inputs					
Differential Input Threshold Voltage, V _{TH}	-200	-125	-30	mV	$-7 \text{ V} \leq \text{V}_{\text{CM}} \leq +12 \text{ V}$
Input Hysteresis		20		mV	$-7 \text{ V} \leq \text{V}_{\text{CM}} \leq +12 \text{ V}$
Input Resistance (A, B)	96	150		kΩ	$-7 \text{ V} \leq \text{V}_{\text{CM}} \leq +12 \text{ V}$
Input Current (A, B)			0.125	mA	$V_{IN} = +12 V$
·			-0.1	mA	$V_{IN} = -7 \text{ V}$
RxD Logic Output					
Output High Voltage	V _{DD1} - 0.1			V	$I_{OUT} = 20 \mu A$, $V_A - V_B = 0.2 V$
	V _{DD1} - 0.4	$V_{DD1} - 0.2$		V	$I_{OUT} = 4 \text{ mA}, V_A - V_B = 0.2 \text{ V}$
Output Low Voltage			0.1	V	$I_{OUT} = -20 \mu A$, $V_A - V_B = -0.2 V$
			0.4	V	$I_{OUT} = -4 \text{ mA}, V_A - V_B = -0.2 \text{ V}$
Output Short-Circuit Current	7		85	mA	$V_{OUT} = GND \text{ or } V_{CC}$
Three-State Output Leakage Current			±1	μΑ	$0.4 \text{ V} \le V_{\text{OUT}} \le 2.4 \text{ V}$
POWER SUPPLY CURRENT					
Logic Side			2.5	mA	$\frac{4.5 \text{ V} \le \text{V}_{DD1} \le 5.5 \text{ V}}{\text{RE}} = 0 \text{ V}$
			1.3	mA	$\frac{2.7 \text{ V} \le \text{V}_{\text{DD1}} \le 3.3 \text{ V}$, outputs unloaded, $\overline{\text{RE}} = 0 \text{ V}$
Bus Side			2.0	mA	Outputs unloaded, DE = 5 V
			1.7	mA	Outputs unloaded, DE = 0 V
COMMON-MODE TRANSIENT IMMUNITY ¹	25			kV/μs	$TxD = V_{DD1}$ or 0 V, $V_{CM} = 1$ kV, transient magnitude = 800 V

 $^{^1}$ Common-mode transient immunity is the maximum common-mode voltage slew rate that can be sustained while maintaining specification-compliant operation. V_{CM} is the common-mode potential difference between the logic and bus sides. The transient magnitude is the range over which the common mode is slewed. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

TIMING SPECIFICATIONS

 $2.7 \leq V_{\rm DD1} \leq 5.5$ V, 4.75 V $\leq V_{\rm DD2} \leq 5.25$ V, $T_{\rm A} = T_{\rm MIN}$ to $T_{\rm MAX}$, unless otherwise noted.

Table 2.

Parameter	Min	Тур	Max	Unit	Test Conditions/Comments
DRIVER					
Maximum Data Rate	500			kbps	
Propagation Delay, tplh, tphl	250		620	ns	$R_{LDIFF} = 54 \Omega$, $C_{L1} = C_{L2} = 100 pF$, see Figure 5 and Figure 9
Skew, t _{skew}			40	ns	$R_{LDIFF} = 54 \Omega$, $C_{L1} = C_{L2} = 100 pF$, see Figure 5 and Figure 9
Rise/Fall Time, t _R , t _F	200		600	ns	$R_{LDIFF} = 54 \Omega$, $C_{L1} = C_{L2} = 100 pF$, see Figure 5 and Figure 9
Enable Time			1050	ns	$R_L = 500 \Omega$, $C_L = 100 pF$, see Figure 6 and Figure 11
Disable Time			1050	ns	$R_L = 500 \Omega$, $C_L = 15 pF$, see Figure 6 and Figure 11
RECEIVER					
Propagation Delay, tplh, tphl	400		1050	ns	$C_L = 15$ pF, see Figure 7 and Figure 10
Differential Skew, t _{SKEW}			250	ns	$C_L = 15$ pF, see Figure 7 and Figure 10
Enable Time		25	70	ns	$R_L = 1 \text{ k}\Omega$, $C_L = 15 \text{ pF}$, see Figure 8 and Figure 12
Disable Time		40	70	ns	$R_L = 1 \text{ k}\Omega$, $C_L = 15 \text{ pF}$, see Figure 8 and Figure 12
POWER VALID INPUT					
Enable Time		1	2	μs	
Disable Time		3	5	μs	

ABSOLUTE MAXIMUM RATINGS

 $T_A = 25$ °C, unless otherwise noted. All voltages are relative to their respective ground.

Table 3.

Tuble 5.	
Parameter	Rating
V _{DD1}	−0.5 V to +7 V
V_{DD2}	−0.5 V to +6 V
Digital Input Voltage (DE, RE, TxD)	$-0.5 \text{ V to V}_{DD1} + 0.5 \text{ V}$
Digital Output Voltage	
RxD	$-0.5 \text{ V to V}_{DD1} + 0.5 \text{ V}$
Driver Output/Receiver Input Voltage	−9 V to +14 V
ESD Rating: Contact (Human Body Model) (A, B Pins)	±2 kV
Operating Temperature Range	-40°C to +85°C
Storage Temperature Range	−55°C to +150°C
Average Output Current per Pin	-35 mA to +35 mA
θ_{JA} Thermal Impedance	73°C/W
Lead Temperature	
Soldering (10 sec)	260°C
Vapor Phase (60 sec)	215°C
Infrared (15 sec)	220°C
Infrared (15 sec)	220°C

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Table 4. Maximum Continuous Working Voltage¹

Parameter	Max	Unit	Reference Standard
AC Voltage			
Bipolar Waveform			
Basic Insulation	565	V_{PEAK}	50-year minimum lifetime
Reinforced Insulation	565	V_{PEAK}	50-year minimum lifetime
Unipolar Waveform			
Basic Insulation	1131	V_{PEAK}	50-year minimum lifetime
Reinforced Insulation	864	VPEAK	Lifetime limited by package creepage maximum approved working voltage per IEC 60950-1
DC Voltage			
Basic Insulation	1066	V _{PEAK}	Lifetime limited by package creepage maximum approved working voltage per IEC 60950-1
Reinforced Insulation	529	VPEAK	Lifetime limited by package creepage maximum approved working voltage per IEC 60950-1

¹ Refers to continuous voltage magnitude imposed across the isolation barrier.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PACKAGE CHARACTERISTICS

Table 5.

Parameter	Symbol	Min	Тур	Max	Unit	Test Conditions
Resistance (Input-Output) ¹	R _{I-O}		10 ¹²		Ω	
Capacitance (Input-Output) ¹	C _{I-O}		3		рF	f = 1 MHz
Input Capacitance ²	Cı		4		рF	
Input IC Junction-to-Case Thermal Resistance	θ _{ЈСІ}		33		°C/W	Thermocouple located at center of package underside
Output IC Junction-to-Case Thermal Resistance	θιςο		28		°C/W	Thermocouple located at center of package underside

Device considered a 2-terminal device: Pins 1, 2, 3, 4, 5, 6, 7, and 8 shorted together, and Pins 9, 10, 11, 12, 13, 14, 15, and 16 shorted together.

REGULATORY INFORMATION

The ADM2483 has been approved by the following organizations:

Table 6.

UL ¹	CSA	cqc	VDE ²
Recognized Under 1577 Component Recognition Program	Approved under CSA Component Acceptance Notice 5A	Approved Under CQC11-471543-2012	Certified according to DIN V VDE V 0884-10 (VDE V 0884-10): 2006-12
	IEC 609501 800 V rms (1131 V _{PEAK}) basic, 400 V rms (565 V _{PEAK}) reinforced	Basic insulation per GB4943.1-2011, 415 V rms (588 V _{PEAK}) maximum working voltage, tropical climate, altitude ≤ 5000 meters	
File E214100	File 205078	File CQC14001114898	File 2471900-4880-0001

¹ In accordance with UL1577, each ADM2483 is proof tested by applying an insulation test voltage \geq 3000 V rms for 1 sec (current leakage detection limit = 5 μ A).

INSULATION AND SAFETY-RELATED SPECIFICATIONS

Table 7.

Parameter	Symbol	Value	Unit	Conditions
Rated Dielectric Insulation Voltage		2500	V rms	1-minute duration
Minimum External Air Gap (Clearance)	L(I01)	7.45 min	mm	Measured from input terminals to output terminals, shortest distance through air
Minimum External Tracking (Creepage)	L(I02)	8.1 min	mm	Measured from input terminals to output terminals, shortest distance along body
Minimum Internal Gap (Internal Clearance)		0.017 min	mm	Insulation distance through insulation
Tracking Resistance (Comparative Tracking Index)	CTI	>400	V	DIN IEC 112/VDE 0303 Part 1
Isolation Group		II		Material Group (Table 1 in DIN VDE 0110,1/89)

² Input capacitance is from any input data pin to ground.

² In accordance with VDE V 0884-10, each ADM2483 is proof tested by applying an insulation test voltage ≥1050 V_{PEAK} for 1 sec (partial discharge detection limit = 5 pC).

VDE V 0884-10 INSULATION CHARACTERISTICS

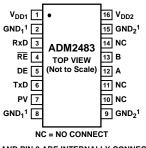
This isolator is suitable for reinforced electrical isolation only within this safety limit data. Maintenance of this safety data shall be ensured by means of protective circuits.

An asterisk (*) on the physical package denotes VDE V 0884-10 approval for 560 V peak working voltage.

Table 8.

Description	Symbol	Characteristic	Unit
Installation Classification per DIN VDE 0110 for Rated Mains Voltage			
≤150 V rms		I to IV	
≤300 V rms		I to III	
≤400 V rms		I to II	
Climatic Classification		40/100/21	
Pollution Degree (Table 1 in DIN VDE 0110)		2	
Maximum Working Insulation Voltage	V _{IORM}	560	V_{PEAK}
Input to Output test Voltage, Method b1	V_{PR}	1050	V_{PEAK}
$V_{IORM} \times 1.875 = V_{PR}$, 100% Production Tested			
$t_m = 1$ sec, Partial Discharge <5 pC			
Input-to-Output Test Voltage, Method a			
(After Environmental Tests, Subgroup 1)			
$V_{IORM} \times 1.6 = V_{PR}$, $t_m = 60$ sec, Partial Discharge <5 pC		896	V_{PEAK}
(After Input and/or Safety Test, Subgroup 2/3)			
$V_{IORM} \times 1.2 = V_{PR}$, $t_m = 60$ sec, Partial Discharge < 5 pC	V_{PR}	672	V_{PEAK}
Highest Allowable Overvoltage			
(Transient Overvoltage, $t_{TR} = 10$ sec)	V_{TR}	4000	V_{PEAK}
Safety-Limiting Values (Maximum Value Allowed in the Event of a Failure. See Figure 23.)			
Case Temperature	Ts	150	°C
Input Current	I _{S, INPUT}	265	mA
Output Current	Is, оитрит	335	mA
Insulation Resistance at T_S , $V_{IO} = 500 \text{ V}$	Rs	>109	Ω

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



¹ PIN 2 AND PIN 8 ARE INTERNALLY CONNECTED. EITHER OR BOTH MAY BE USED FOR GND₁. PIN 9 AND PIN 15 ARE INTERNALLY CONNECTED. EITHER OR BOTH MAY BE USED FOR GND₂.

Figure 2. Pin Configuration

Table 9. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	V _{DD1}	Power Supply (Logic Side).
2, 8	GND ₁	Ground (Logic Side).
3	RxD	Receiver Output Data. When enabled, if $(A - B) \ge -30$ mV, then RxD = high. If $(A - B) \le -200$ mV, then RxD = low. This is a tristate output when the receiver is disabled, that is, when \overline{RE} is driven high.
4	RE	Receiver Enable Input. This is an active-low input. Driving this input low enables the receiver, and driving it high disables the receiver.
5	DE	Driver Enable Input. Driving the input high enables the driver, and driving it low disables the driver.
6	TxD	Transmit Data Input. Data to be transmitted by the driver is applied to this input.
7	PV	Power_Valid. Used during power-up and power-down. See the Applications Information section.
9, 15	GND ₂	Ground (Bus Side).
10, 11, 14	NC	No Connect.
12	A	Noninverting Driver Output/Receiver Input. When the driver is disabled, or when V_{DD1} or V_{DD2} is powered down, Pin A is put into a high impedance state to avoid overloading the bus.
13	В	Inverting Driver Output/Receiver Input. When the driver is disabled, or when V _{DD1} or V _{DD2} is powered down, Pin B is put into a high impedance state to avoid overloading the bus.
16	V_{DD2}	Power Supply (Bus Side).

TEST CIRCUITS

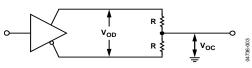


Figure 3. Driver Voltage Measurement

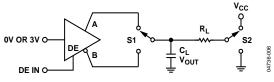


Figure 6. Driver Enable/Disable

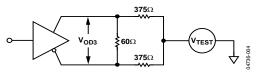


Figure 4. Driver Voltage Measurement

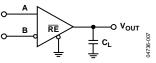


Figure 7. Receiver Propagation Delay

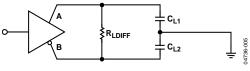


Figure 5. Driver Propagation Delay

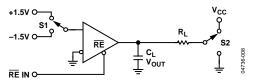


Figure 8. Receiver Enable/Disable

SWITCHING CHARACTERISTICS

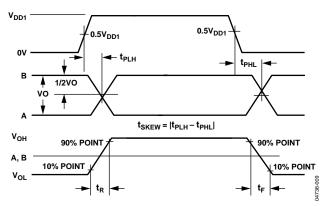
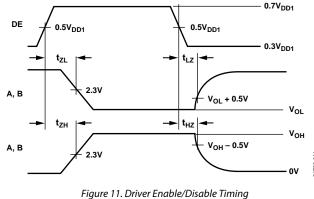


Figure 9. Driver Propagation Delay, Rise/Fall Timing



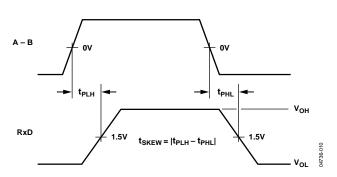


Figure 10. Receiver Propagation Delay

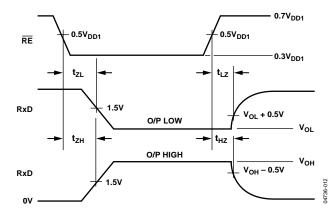


Figure 12. Receiver Enable/Disable Timing

TYPICAL PERFORMANCE CHARACTERISTICS

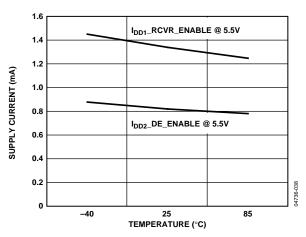


Figure 13. Unloaded Supply Current vs. Temperature

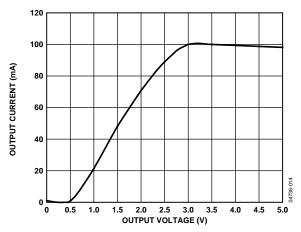


Figure 14. Output Current vs. Driver Output Low Voltage

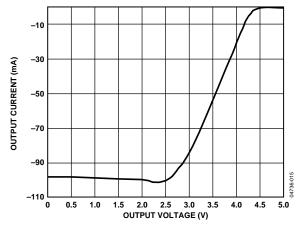


Figure 15. Output Current vs. Driver Output High Voltage

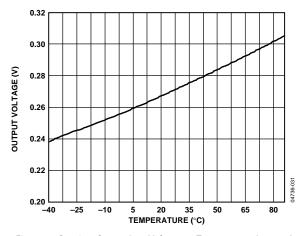


Figure 16. Receiver Output Low Voltage vs. Temperature, I = -4mA

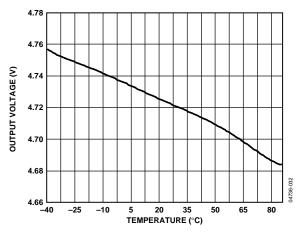


Figure 17. Receiver Output High Voltage vs. Temperature, I = 4 mA

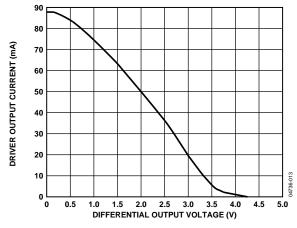


Figure 18. Driver Output Current vs. Differential Output Voltage

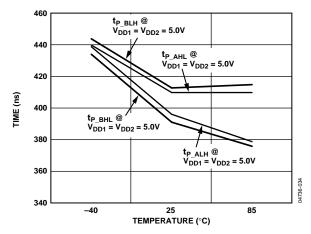


Figure 19. Driver Propagation Delay vs. Temperature

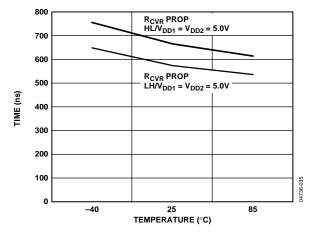


Figure 20. Receiver Propagation Delay vs. Temperature

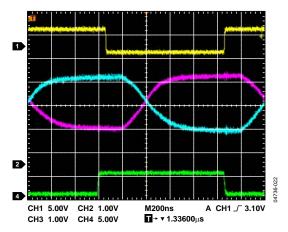


Figure 21. Driver/Receiver Propagation Delay High to Low

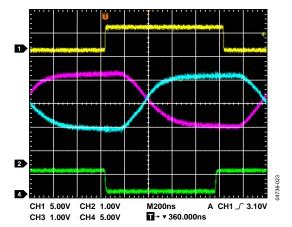


Figure 22. Driver/Receiver Propagation Delay Low to High

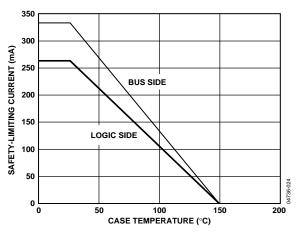


Figure 23. Thermal Derating Curve, Dependence of Safety-Limiting Values with Case Temperature per VDE V 0884

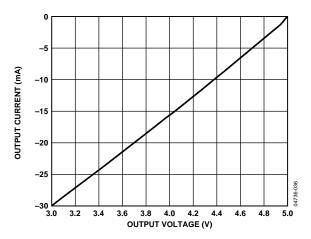


Figure 24. Output Current vs. Receiver Output High Voltage

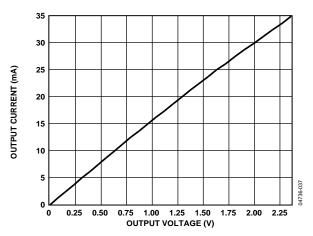


Figure 25. Output Current vs. Receiver Output Low Voltage

CIRCUIT DESCRIPTION ELECTRICAL ISOLATION

In the ADM2483, electrical isolation is implemented on the logic side of the interface. Therefore, the part has two main sections: a digital isolation section and a transceiver section (see Figure 26). Driver input and data enable signals, applied to the TxD and DE pins, respectively, and referenced to logic ground (GND1), are coupled across an isolation barrier to appear at the transceiver section referenced to isolated ground (GND2). Similarly, the receiver output, referenced to isolated ground in the transceiver section, is coupled across the isolation barrier to appear at the RxD pin referenced to logic ground.

iCoupler Technology

The digital signals are transmitted across the isolation barrier using *i*Coupler technology. This technique uses chip-scale transformer windings to couple the digital signals magnetically from one side of the barrier to the other. Digital inputs are encoded into waveforms that are capable of exciting the primary transformer winding. At the secondary winding, the induced waveforms are then decoded into the binary value that was originally transmitted.

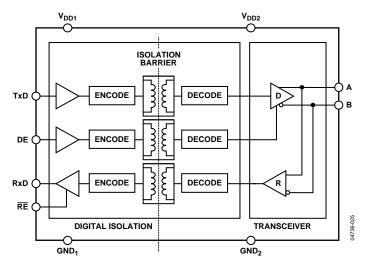


Figure 26. ADM2483 Digital Isolation and Transceiver Sections

TRUTH TABLES

The following truth tables use these abbreviations:

Letter	Description
Н	High level
L	Low level
Χ	Irrelevant
Z	High impedance (off)
NC	Disconnected

Table 10. Transmitting

Supply Status		Inp	uts	Outputs	
V _{DD1}	V_{DD2}	DE TxD		Α	В
On	On	Н	Н	Н	L
On	On	Н	L	L	Н
On	On	L	Χ	Z	Z
On	Off	Χ	Χ	Z	Z
Off	On	X	Χ	Z	Z
Off	Off	Χ	Χ	Z	Z

Table 11. Receiving

Supply Status		Inputs		Outputs	
V_{DD1}	V _{DD2}	A – B (V)	RE	RxD	
On	On	>-0.03	L or NC	Н	
On	On	<-0.2	L or NC	L	
		-0.2 < A - B <			
On	On	-0.03	L or NC	Indeterminate	
On	On	Inputs open	L or NC	Н	
On	On	Х	Н	Z	
On	Off	Х	L or NC	Н	
Off	On	Х	L or NC	Н	
Off	Off	X	L or NC	L	

POWER-UP/POWER-DOWN CHARACTERISTICS

The power-up/power-down characteristics of the ADM2483 are in accordance with the supply thresholds shown in Table 12. Upon power-up, the ADM2483 output signals (A, B, and RxD) reach their correct state once both supplies exceed their thresholds. Upon power-down, the ADM2483 output signals retain their correct state until at least one of the supplies drops below its power-down threshold. When the $V_{\rm DD1}$ power-down threshold is crossed, the ADM2483 output signals reach their unpowered states within 4 μ s.

Table 12. Power-Up/Power-Down Thresholds

Supply	Transition	Threshold (V)		
V _{DD1}	Power-up	2.0		
V_{DD1}	Power-down	1.0		
V_{DD2}	Power-up	3.3		
V_{DD2}	Power-down	2.4		

THERMAL SHUTDOWN

The ADM2483 contains thermal shutdown circuitry that protects the part from excessive power dissipation during fault conditions. Shorting the driver outputs to a low impedance source can result in high driver currents. The thermal sensing circuitry detects the increase in die temperature under this condition and disables the driver outputs. This circuitry is designed to disable the driver outputs when a die temperature of 150°C is reached. As the device cools, the drivers are re-enabled at a temperature of 140°C.

TRUE FAIL-SAFE RECEIVER INPUTS

The receiver inputs have a true fail-safe feature, which ensures that the receiver output is high when the inputs are open or shorted. During line-idle conditions, when no driver on the bus is enabled, the voltage across a terminating resistance at the receiver input decays to 0 V. With traditional transceivers, receiver input thresholds specified between -200~mV and +200~mV mean that external bias resistors are required on the A and B pins to ensure that the receiver outputs are in a known state. The true fail-safe receiver input feature eliminates the need for bias resistors by specifying the receiver input threshold between -30~mV and -200~mV. The guaranteed negative threshold means that when the voltage between A and B decays to 0 V, the receiver output is guaranteed to be high.

MAGNETIC FIELD IMMUNITY

Because *i*Couplers use a coreless technology, no magnetic components are present, and the problem of magnetic saturation of the core material does not exist. Therefore, *i*Couplers have essentially infinite dc field immunity. The analysis that follows defines the conditions under which this might occur. The ADM2483's 3 V operating condition is examined because it represents the most susceptible mode of operation.

The limitation on the *i*Coupler's ac magnetic field immunity is set by the condition in which the induced error voltage in the receiving coil (the bottom coil in this case) is made sufficiently large, either to falsely set or reset the decoder. The voltage induced across the bottom coil is given by

$$V = \left(\frac{-d\beta}{dt}\right) \sum \pi r_n^2; \quad n = 1, 2, \dots, N$$

where if the pulses at the transformer output are greater than 1.0 V in amplitude:

 β = magnetic flux density (gauss)

N = number of turns in receiving coil

 r_n = radius of nth turn in receiving coil (cm)

The decoder has a sensing threshold of about 0.5 V; therefore, there is a 0.5 V margin in which induced voltages can be tolerated

Given the geometry of the receiving coil and an imposed

requirement that the induced voltage is, at most, 50% of the 0.5 V margin at the decoder, a maximum allowable magnetic field is calculated, as shown in Figure 27.

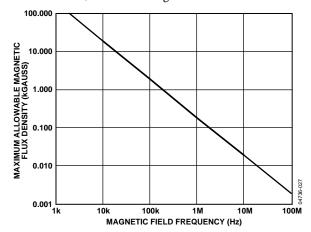


Figure 27. Maximum Allowable External Magnetic Flux Density

For example, at a magnetic field frequency of 1 MHz, the maximum allowable magnetic field of 0.2 kGauss induces a voltage of 0.25 V at the receiving coil. This is about 50% of the sensing threshold and does not cause a faulty output transition. Similarly, if such an event occurs during a transmitted pulse and is the worst-case polarity, it reduces the received pulse from $>\!1.0~{\rm V}$ to 0.75 V. This is well above the 0.5 V sensing threshold of the decoder.

These magnetic flux density values are shown in Figure 28, using more familiar quantities such as maximum allowable current flow, at given distances away from the ADM2483 transformers.

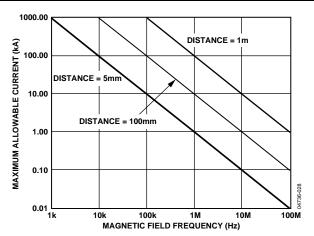


Figure 28. Maximum Allowable Current for Various Current-to-ADM2483 Spacings

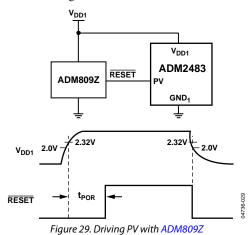
At combinations of strong magnetic field and high frequency, any loops formed by printed circuit board traces could induce large enough error voltages to trigger the thresholds of succeeding circuitry. To avoid this possibility, care should be taken in the layout of such traces.

APPLICATIONS INFORMATION

POWER_VALID INPUT

To avoid chatter on the A and B outputs caused by slow power-up and power-down transients on $V_{\rm DD1}$ (>100 $\mu s/V$), the ADM2483 features a power_valid (PV) digital input. This pin should be driven low until $V_{\rm DD1}$ exceeds 2.0 V. When $V_{\rm DD1}$ is greater than 2.0 V, the pin should be driven high. Conversely, upon power-down, the PV should be driven low before $V_{\rm DD1}$ reaches 2.0 V.

The power_valid input can be driven, for example, by the output of a system reset circuit such as the ADM809Z, which has a threshold voltage of 2.32 V.



ISOLATED POWER SUPPLY CIRCUIT

The ADM2483 requires isolated power capable of 5 V at 100 mA to be supplied between the $V_{\rm DD2}$ and GND_2 pins. If no suitable integrated power supply is available, a discrete circuit, such as the one in Figure 30, can be used. A center-tapped transformer provides electrical isolation. The primary winding is excited with a pair of square waveforms that are 180° out of phase with each other. A pair of Schottky diodes and a smoothing capacitor are used to create a rectified signal from the secondary winding. The ADP667 linear voltage regulator provides a regulated power supply to the ADM2483's bus-side circuitry.

To create the pair of square waves, a D-type flip-flop with complementary Q/\overline{Q} outputs is used. The flip-flop can be connected so that output Q follows the clock input signal. If no local clock signal is available, a simple digital oscillator can be implemented with a hex-inverting Schmitt trigger and a resistor and capacitor. In this case, values of 3.9 k Ω and 1 nF generate a 364 kHz square wave. A pair of discrete NMOS transistors, switched by the Q/\overline{Q} flip-flop outputs, conduct current through the center tap of the primary transformer, winding in an alternating fashion.

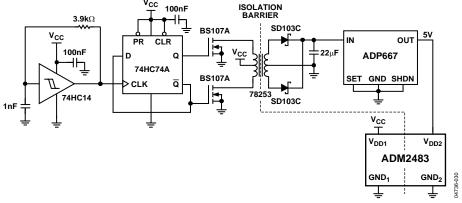
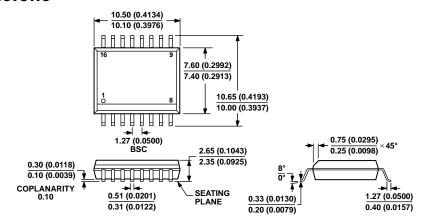


Figure 30. Isolated Power Supply Circuit

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-013-AA
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 31. 16-Lead Standard Small Outline Package [SOIC_W] Wide Body (RW-16) Dimensions shown in millimeters and (inches)

ORDERING GUIDE

Model ^{1, 2}	Data Rate (kbps)	Temperature Range	Package Description	Package Option
ADM2483BRW	500	−40°C to +85°C	16-Lead, Wide Body SOIC_W	RW-16
ADM2483BRW-REEL	500	-40°C to +85°C	16-Lead, Wide Body SOIC_W	RW-16
ADM2483BRWZ	500	−40°C to +85°C	16-Lead, Wide Body SOIC_W	RW-16
ADM2483BRWZ-REEL	500	−40°C to +85°C	16-Lead, Wide Body SOIC_W	RW-16
EVAL-ADM2483EBZ			ADM2483 Evaluation Board	

¹ Z = RoHS Compliant Part.

 $^{^{\}rm 2}$ -REEL suffix designates a 13-inch (1,000 units) tape-and-reel option.